

VRE3025

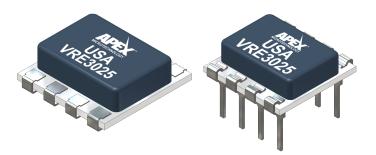
Precision Voltage Reference



FEATURES

- +2.5 V Output, ± 0.375 mV
- Temperature Drift: 1.0 ppm/°C
- Low Noise: 1.5 μV_{P-P} (0.1 Hz-10 Hz)
- Low Thermal Hysteresis: 1 ppm Typical
- ±15 mA Output Source and Sink Current
- Excellent Line Regulation: 5 ppm/V Typical
- Optional Noise Reduction and Voltage Trim
- Industry Standard Pinout: 8-pin DIP or
- Surface Mount Package

APPLICATIONS



The VRE3025 is recommended for use as a reference for 14 and 16 bit data converters which require an external precision reference. The device is also ideal for calibrating scale factor on high resolution data converters. The VRE3025 offers superior performance over monolithic references.

DESCRIPTION

The VRE3025 is a low cost, high precision +2.5 V reference that operates from +10 V. The device features a buried zener for low noise and excellent long term stability. Packaged in either an 8-pin DIP or SMT option, the device is ideal for high resolution data conversion systems.

The device provides ultrastable +2.5 V output with ±0.375 mV initial accuracy and a temperature coefficient of 1.0 ppm/°C. This improvement in accuracy is made possible by a unique, patented multi-point laser compensation technique. Significant improvements have been made in other performance parameters as well, including initial accuracy, warm-up drift, line regulation, and long-term stability, making the VRE3025 series the most accurate reference available.

For enhanced performance, the VRE3025 has an external trim option for users who want less than 0.375 mV initial error. For ultra low noise applications, an external capacitor can be attached between the noise reduction pin and the ground pin.

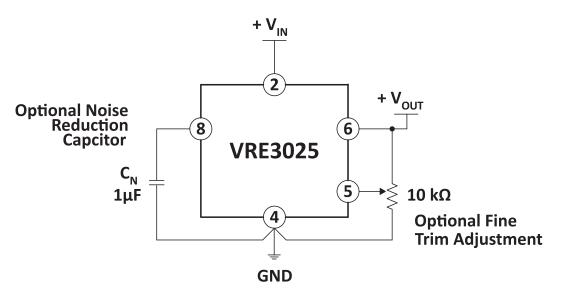
Model	Initial Error (mV)	Temp. Coeff. (ppm/°C)	Temp Range (°C)	Package Options	
VRE3025BS	0.375	1.0	0°C to +70°C	SMT8 (GF)	
VRE3025BD	0.375	1.0	0°C to +70°C	DIP8 (KD)	
VRE3025JS	0.250	0.6	-40°C to +85°C	SMT8 (GF)	
VRE3025LS	0.500	2.0	-40°C to +85°C	SMT8 (GF)	

SELECTION GUIDE



TYPICAL CONNECTION

Figure 1: Typical Connection



PIN DESCRIPTIONS

Pin Number	Name	Description	
1, 3, 7	NC	No connection.	
2	V _{IN}	The supply voltage connection.	
4	GND	Ground.	
5	TRIM	Optional fine adjustment. Connect to a voltage divider between OUT and GND.	
6	OUT	2.5 V output.	
8	NR	Optional noise reduction. Connect a 1μ F capacitor between this pin and GND.	



SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Unit
Power Supply	V _{IN}	-0.3	+40	V
Out, Trim		-0.3	+12	V
Noise Reduction	NR	-0.3	+6	V
Operating Temp (B)		0	+70	°C
Operating Temp (J,L)		-40	+85	°C
Out Short Circuit to GND Duration (V _{IN} <12V)			continuous	S
Out Short Circuit to GND Duration (V _{IN} <40V)			5	S
Out Short Circuit to IN Duration (V _{IN} <12V)			continuous	S
Continuous Power Dissipation (T _A = +70°C)			300	mW
Storage Temperature		-65	+150	°C
Lead Temperature (soldering, 10 sec)			+250	°C



ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Voltage	V _{IN}		+8		+36	V
	V _{OUT}	VRE3025J	+2.4998	+2.500	+2.5003	V
Output Voltage ¹		VRE3025B	+2.4996	+2.500	+2.5004	
		VRE3025L	+2.4995	+2.500	+2.5005	
Output Voltage Temperature Coef-		VRE3025J		0.3	0.6	
ficient ²	TCV _{OUT}	VRE3025B		0.5	1.0	ppm/°C
heiem		VRE3025L		1.0	2.0	
Trim Adjustment Range	ΔV _{OUT}	Figure 1		±2.5		mV
Turn-On Settling Time	T _{ON}	To 0.01% of final value		2		μs
Output Noice Voltage		0.1 Hz < f< 10 Hz		1.5		μV _{P-P}
Output Noise Voltage	e _n	10 Hz < f < 1 kHz		1.5	3.0	μV _{RMS}
Temperature Hysterisis ³				1		ppm
Long Term Stability	ΔV _{OUT} /t			6		ppm/ 1000hrs.
Supply Current	I _{IN}			5	7	mA
Load Regulation ⁴	ΔV _{OUT} /	Sourcing: 0mA ≤ I _{OUT} ≤ 15mA		8	12	/m^
	ΔI _{OUT}	Sinking: -15mA≤ I _{OUT} ≤ 0mA		8	12	ppm/mA
Line Regulation ⁴	$\Delta V_{OUT} / \Delta V_{IN}$	$10V \le V_{IN} \le 18V$		5	10	ppm/V

1. The specified values are without external trim.

2. The temperature coefficient is determined by the box method. See discussion on temperature performance.

3. Hysterisis over the operating temperature range.

4. Line and load regulation are measured with pulses and do not include voltage changes due to temperature.



TYPICAL PERFORMANCE GRAPHS

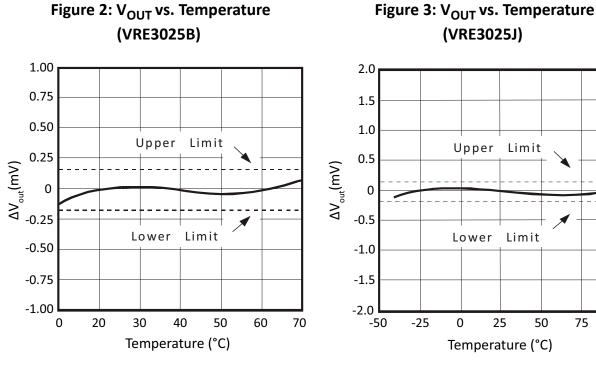
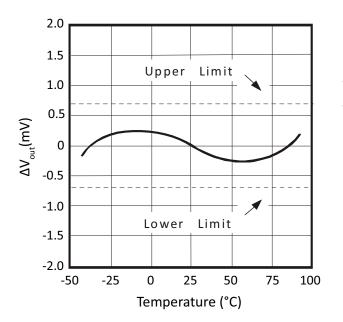


Figure 4: V_{OUT} vs. Temperature (VRE3025L)





25

Temperature (°C)

Upper

Lower

0

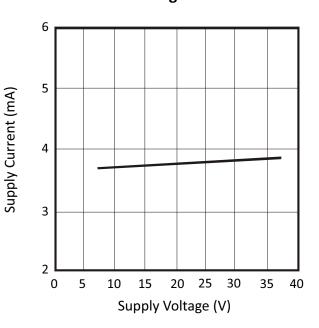
Limit

Limit

50

75

100





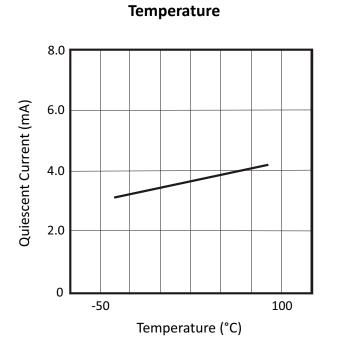


Figure 6: Quiescent Current vs.

Figure 7: Output Impedance vs. Frequency

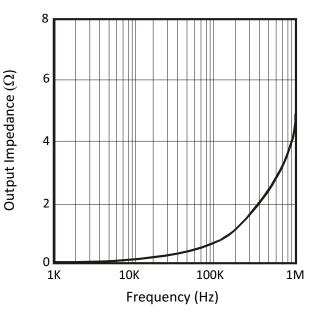
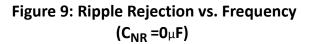
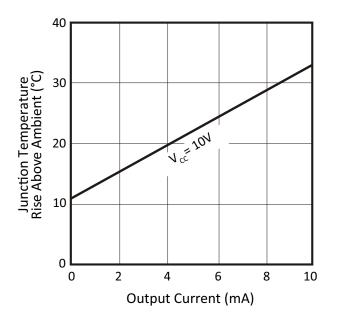


Figure 8: Junction Temp. Rise vs. Output Current





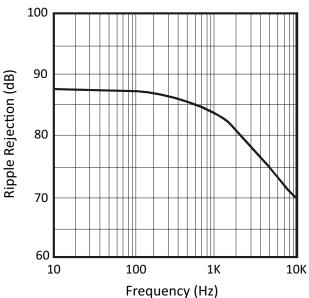
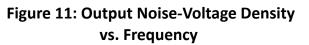




Figure 10: Turn-On and Turn-Off Transient Response



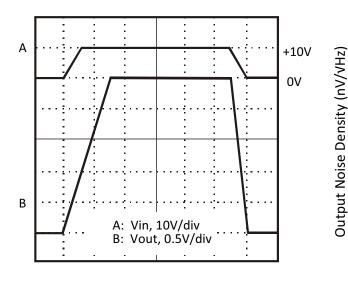
50

40

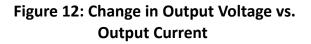
30

20

10 L 10



1 μs/div



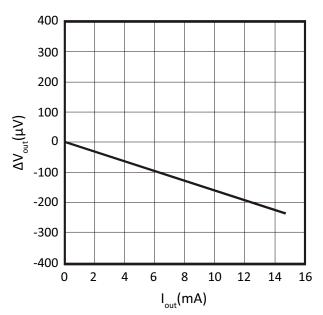


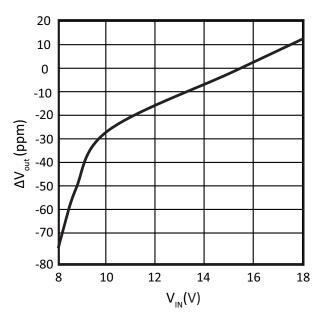
Figure 13: Change in Output Voltage vs. Input Voltage

Frequenzy (Hz)

1K

10K

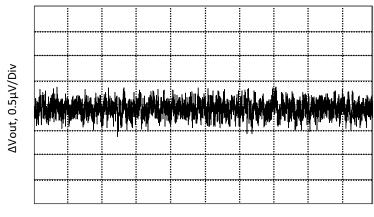
100



VRE3025U Rev M



Figure 14: 0.1 Hz to 10 Hz Noise

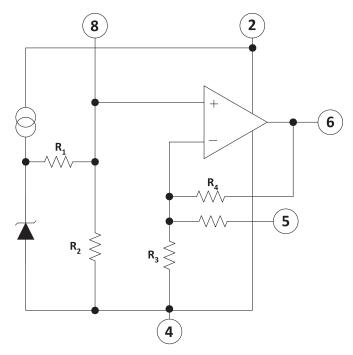


1 sec/Div



BLOCK DIAGRAM





THEORY OF OPERATION

The following discussion refers to the block diagram in Figure 15. A FET current source is used to bias a 6.3 V zener diode. The zener voltage is divided by the resistor network R1 and R2. This voltage is then applied to the non-inverting input of the operational amplifier which amplifies the voltage to produce a 2.5 V output. The gain is determined by the resistor networks R3 and R4: G=1 + R4/R3. The 6.3 V zener diode is used because it is the most stable diode over time and temperature.

The current source provides a closely regulated zener current, which determines the slope of the references' voltage vs. temperature function. By trimming the zener current a lower drift over temperature can be achieved. But since the voltage vs. temperature function is nonlinear this compensation technique is not well suited for wide temperature ranges.

A nonlinear compensation network of thermistors and resistors that is used in the VRE series voltage references. This proprietary network eliminates most of the nonlinearity in the voltage vs. temperature function. By adjusting the slope, a very stable voltage is produced over wide temperature ranges.

This network is less than 2% of the overall network resistance so it has a negligible effect on long term stability. The proper connection of the VRE3025 series voltage references with the optional trim resistor for initial error and the optional capacitor for noise reduction is shown above.



BASIC CIRCUIT CONNECTION

To achieve the specified performance, pay careful attention to the layout. A low resistance star configuration will reduce voltage errors, noise pickup, and noise coupled from the power supply. Commons should be connected to a single point to minimize interconnect resistances.

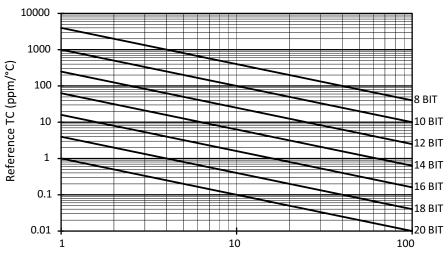


Figure 16: TC vs. ΔT Change from 25°C for 1 LSB Change

Reference TC vs. Δ T change from 25°C for 1 LSB change (°C)

TEMPERATURE PERFORMANCE

The VRE3025 is designed for applications where the initial error at room temperature and drift over temperature are important to the user. For many instrument manufacturers, a voltage reference with a temperature coefficient less than 1 ppm/°C makes it possible to not have to perform a system temperature calibration, a slow and costly process.

Of the three TC specification methods (slope, butterfly, and box), the box method is commonly used. A box is formed by the min/max limits for the nominal output voltage over the operating temperature range. The equation follows:

$$TC = \frac{V_{MAX} - V_{MIN}}{V_{NOMINAL} \times (T_{MAX} - T_{MIN})} \times 10^{6}$$

This method corresponds more accurately to the method of test and provides a closer estimate of actual error than the other methods. The box method guarantees limits for the temperature error but does not specify the exact shape and slope of the device under test.

A designer who needs a 14-bit accurate data acquisition system over the industrial temperature range (-40°C to +85°C), will need a voltage reference with a temperature coefficient (TC) of 1.0 ppm/°C if the reference is allowed to contribute an error equivalent to 1LSB. For 1/2LSB equivalent error from the reference you would need a voltage reference with a temperature coefficient of 0.5 ppm/°C. Figure 16 shows the required reference TC vs. delta T change from 25°C for resolution ranging from 8 bits to 20 bits.



THERMAL HYSTERISIS

A change in output voltage as a result of a temperature change. When references experience a temperature change and return to the initial temperature, they do not always have the same initial voltage. Thermal hysterisis is difficult to correct and is a major error source in systems that experience temperature changes greater than 25°C. Reference vendors are starting to include this important specification in their datasheets.

PIN CONFIGURATION

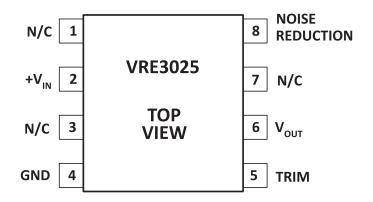


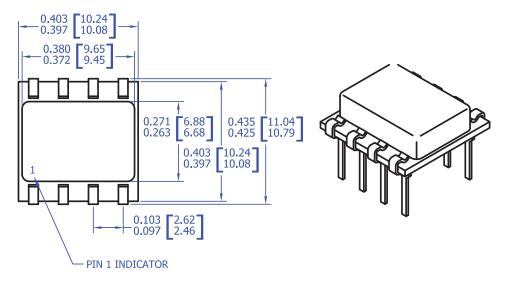
Figure 17: Pin Configuration

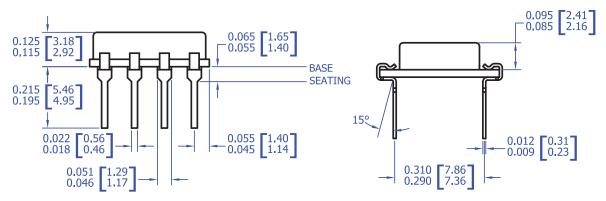


PACKAGE OPTIONS

Part Number	Apex Package Style	Description
VRE3025BD	KD	8-pin DIP
VRE3025BS	GF	8-pin Surface Mount DIP
VRE3025JS	GF	8-pin Surface Mount DIP
VRE3025LS	GF	8-pin Surface Mount DIP

PACKAGE STYLE KD





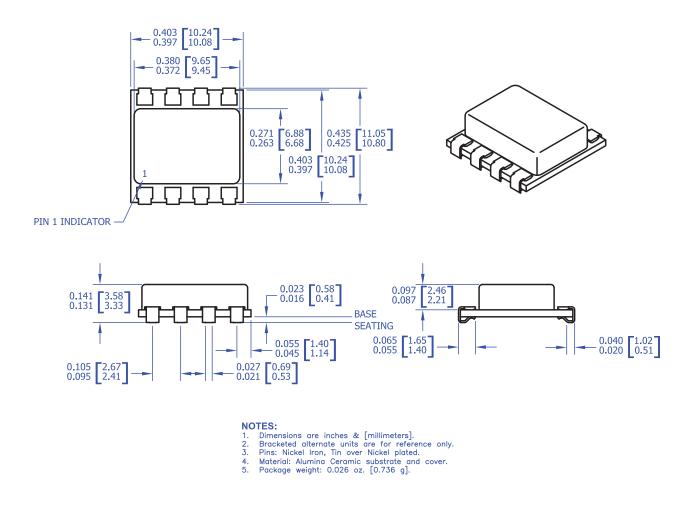
NOTES:

- 1. Dimensions are inches & [millimeters].
- Bracketed alternate units are for reference only. Pins: Phosphor bronze, Sn/Ag 96/4 solder dipped. 2.
- 3.
- Material: Alumina Ceramic substrate and cover.
 Package weight: 0.028 oz. [0.785 g].



VRE3025

PACKAGE STYLE GF



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